

Development of Polysilane-Inserted Perovskite Solar Cells [†]

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Abstract: Perovskite solar cells, in which decaphenylcyclopentasilane (DPPS) layers were formed on the surface of the CH₃NH₃PbI₃-based perovskite layer, were developed. The photovoltaic properties were improved by controlling the annealing temperature of the perovskite layer. For perovskite layers annealed at high temperatures in the range of 180–220 °C, the perovskite crystals were densely formed and the surface coverage of the perovskite layer was improved. The DPPS-laminated devices suppressed the formation of PbI₂ crystals and the stability was improved by the DPPS layer. Furthermore, the conversion efficiencies were improved over extended periods of time.

Keywords: polysilane; decaphenylcyclopentasilane; perovskite; photovoltaic device; solar cell; formamidinium; potassium

1. Introduction

The most commonly used solar cells are currently silicon-based solar cells. However, these silicon devices have a complicated fabrication process, and the silicon semiconductor has an indirect transition band structure. On the other hand, recently developed CH₃NH₃PbI₃ (MAPbI₃)-based perovskite compounds have demonstrated numerous advantages, such as direct bandgaps, easy fabrication process, and high conversion efficiencies [1,2]. Therefore, these compounds are considered as major candidates for next-generation solar cell materials. However, these lead halide compounds are typically unstable in air, and the stability of the corresponding perovskite photovoltaic devices should be improved for inclusion in the actual cell module. The instability of the perovskite photovoltaic devices results from the migration of CH₃NH₃ (MA) and iodine (I), and reactivity with H₂O [3,4].

To improve these stability of the perovskite photovoltaic devices, polymeric materials have been investigated [5–7]. For instance, poly(methyl methacrylate) and poly(propylene carbonate) have been used to protect the perovskite layer from oxygen and moisture [8,9] and to enhance stability. Both polymeric materials formed cross-linked networks comprising perovskite grains, which suppressed defects. Furthermore, the stability was also influenced by hole transport layers (HTLs) [10]. In practice, 2,2',7,7'-tetrakis(*N,N*-di-*p*-methoxyphenylamine)-9,9'-spirobifluorene (spiro-OMeTAD) is widely applied as a HTL for perovskite photovoltaic devices. However, this material is expensive, and the electronic properties degrade at elevated temperatures in air. Various alternative hole

transport materials have been reported [11,12], and polysilane derivatives have also been investigated [13].

Polysilane derivatives exhibit two important advantages. The first relates to polysilanes being *p*-type semiconductors that facilitate hole transfer and rectification at the *pn* junction [13]. The second derives from polysilanes having high stabilities at elevated temperatures up to ~300 °C and therefore expected to act as a protective layer across the perovskite surface. In addition, polysilanes have been applied to perovskite solar cells [14], and the photovoltaic properties were improved, especially by adding decaphenylcyclopentasilane (DPPS) [15,16]. The previously reported perovskite layers were a standard MAPbI₃ compound, so further studies focusing on doped MAPbI₃ compounds [17–19] are required to further elucidate the applicability of DPPS for perovskite solar cells.

Another method to improve the stability of perovskite solar cells is elemental or molecular doping of the perovskite crystals. The general formula of perovskite compounds is ABX₃, where A and B are cations and X is an anion. The perovskite crystal with a cubic system has the B cations in sixfold coordination, surrounded by an octahedron of X anions and the A cation in octahedral coordination. The perovskite crystal of CH₃NH₃PbI₃ is constructed with a Pb²⁺ cation at the B-site, I⁻ anion at the X-site, and CH₃NH₃⁺ cation at the A-site. To estimate and predict the structural stabilities of the perovskite compounds, indicators called tolerance factors (*t*) have been calculated and used [19,20]. The tolerance factor is calculated as follows:

$$t = \frac{r_A + r_X}{\sqrt{2}(r_B + r_X)} \quad (1)$$

where r_A , r_B , and r_X are the ionic radii of the A, B, and X ions. When *t* is close to 1, the perovskite structure is expected to be more structurally stable, although the ionic properties are not considered. The *t*-factor of MAPbI₃ is calculated to be 0.912 [19], and this indicates MAPbI₃ may be slightly unstable. To increase the *t*-factor and reduce the migration of MA, formamidinium (FA: CH₃(NH₂)₂) with a larger ionic radius (2.53 Å) than MA (2.17 Å) was doped at the MA site, and the stabilities of the perovskite solar cells were improved by FA addition [21,22]. Studies on devices with ethylammonium (EA: CH₃CH₂NH₃) [23,24] or guanidinium (GA: C(NH₂)₃) [25,26] addition to perovskites have also been reported. EA and GA have larger ionic radii (2.74 and 2.78 Å) than MA, and the addition of EA or GA can be expected to improve the structural stability from the viewpoint of the tolerance factors [19] and structural calculations [27,28]. It was reported that the crystallinity and stabilities of the perovskite crystals with EA were higher than those of ordinary MAPbI₃ [29]. Then, EA or GA addition to the perovskite compounds provided surface coatings with fewer defects, highly (100)-oriented crystals, and improved stability of the devices [24,26]. However, it should be noted that excessive addition of EA leads to phase separation, a decrease in crystallinity, and precipitation of PbI₂ as an impurity [30].

Since the above MA, FA, EA, and GA are molecules, they may affect the instabilities of the perovskite crystals. Therefore, substitution of alkali metal elements such as cesium (Cs), rubidium (Rb), potassium (K), and sodium (Na) might be effective in avoiding the migration and desorption of A-site elements in the perovskite crystals. It is also expected that the semiconductor characteristics of the perovskite crystals can be controlled by alkali element doping. Effects of Na and K doping to MAPbI₃ crystals on the electronic structures were investigated by first-principles calculation [31]. Partial substitution of MA with Na or K generated electronic orbitals of Na or K above the conduction band, which would facilitate charge transfer from the alkali metals to the conduction band. This may then accelerate carrier diffusion related to the photovoltaic performances. Conversion efficiencies and stabilities were reported to be improved by adding Cs⁺ and Rb⁺ to perovskite precursor solutions, which increased grain sizes and reduced defect densities [32,33]. Conversion efficiencies were also improved by using K, which offers a lower cost than Rb and Cs. A calculated *t*-factor of K doping alone to MAPbI₃ indicates that the structural stability of perovskite compounds was reduced [19], and other cations with larger cationic radii, such as FA and EA, may be necessary to form more stable perovskite structures.

The purpose of the present work is to investigate the photovoltaic properties and stabilities of DPPS-inserted MAPbI₃ perovskite solar cells doped with potassium (K) and formamidinium (FA),

which are denoted as MA(FA,K)PbI₃. Previously, co-addition of K and FA was reported to be effective for enhancing the photovoltaic properties [34–37]. In the present work, the MAPbI₃ and MA(FA,K)PbI₃ perovskite compounds, prepared at temperatures in the range of 180–220 °C in ambient air, were evaluated in terms of the photovoltaic properties and stability [38,39]. The effects of annealing temperatures and polysilane addition on the microstructures and photovoltaic properties of the MA(FA,K)PbI₃ perovskite solar cells were investigated using current density voltage (*J*-*V*) characteristics and X-ray diffraction (XRD).

2. Materials and Methods

A fabrication process of the present solar cell devices is schematically illustrated in Figure 1. The fabrication conditions were ~27 °C temperature and ~40% humidity in ambient air [40,41]. F-doped tin oxide (FTO, Nippon Sheet Glass Company, Tokyo, Japan, ~10 Ω/□) substrates were cleaned by methanol and acetone in an ultrasonic bath and an ultraviolet ozone cleaner (Asumi Giken, Tokyo, Japan, ASM401N) [18,42]. Next, 0.15 and 0.30 M precursor solutions of TiO₂ compact layers were prepared from 1-butanol (Wako Pure Chemical Industries, Osaka, Japan) and titanium diisopropoxide bis(acetylacetonate) (Sigma Aldrich, Tokyo, Japan). These precursor solutions of compact TiO₂ were spin-coated on the FTO substrate at 3000 rpm for 30 s, and the substrates were annealed at 125 °C for 5 min. To form a uniform compact TiO₂ layer, the 0.30 M precursor solution was spin-coated twice. Then, the FTO substrate was annealed at 550 °C for 30 min to form the compact TiO₂ layer. After that, a TiO₂ paste (precursor solution for mesoporous TiO₂) was spin-coated on the compact TiO₂ layer at 5000 rpm for 30 s. This TiO₂ paste was prepared by mixing distilled water (0.5 mL), poly(ethylene glycol) PEG-20000 (Nacalai Tesque, Kyoto, Japan, PEG #20000, 20 mg), and TiO₂ powder (Aerosil, Tokyo, Japan, P-25, 200 mg). This solution was further mixed with the surfactant Triton X-100 (Sigma Aldrich, 10 μL) and acetylacetone (Wako Pure Chemical Industries, 20 μL) for 30 min, and it was left untouched for 24 h to remove bubbles in the solution [41]. To form the mesoporous TiO₂ layer, the TiO₂-coated substrates were annealed at 550 °C for 30 min.

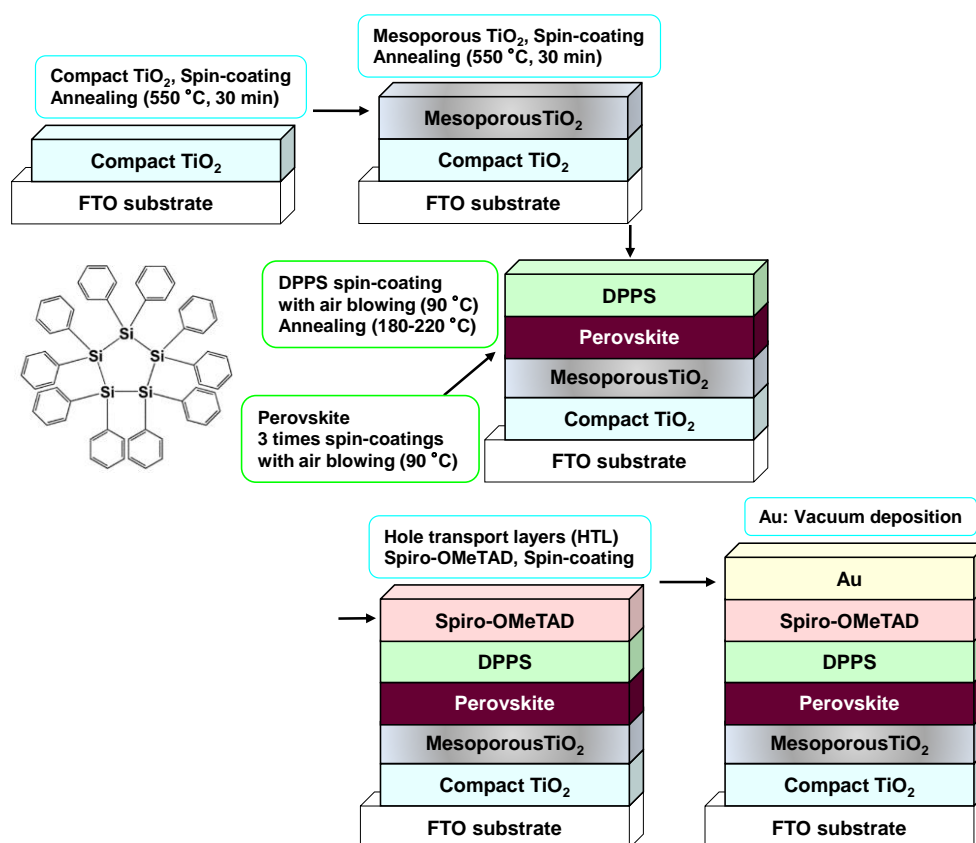


Figure 1. Schematic illustration detailing the processes adopted to fabricate the perovskite photovoltaic devices.

The perovskite compounds were prepared by mixing *N,N*-dimethylformamide (DMF; Sigma Aldrich) solutions of KI (Wako Pure Chemical Industries), $\text{HC}(\text{NH}_2)_2\text{I}$ (Tokyo Chemical Industry, Tokyo, Japan), $\text{CH}_3\text{NH}_3\text{I}$ (Tokyo Chemical Industry), and PbCl_2 (Sigma Aldrich) at 60 °C for 1 day. The basic precursor of MAPbI_3 was prepared with molar concentrations of PbCl_2 and MAI of 0.8 and 2.4 M, respectively [41,43], and $\text{MA}_{0.64}\text{FA}_{0.31}\text{K}_{0.05}\text{PbI}_3$ and $\text{MA}_{0.48}\text{FA}_{0.47}\text{K}_{0.05}\text{PbI}_3$ precursors were prepared by adding FAI and KI to control the desired molar ratio [38]. As the FA composition increased, the tolerance factor (*t*-factor) increased toward 1 [19], which indicated the crystal distortion in the perovskite structure could be reduced by FA addition. Perovskite precursor solutions were spin-coated on the mesoporous TiO_2 layer three times. For the first spin-coating, the perovskite solutions were spin-coated at 2000 rpm for 60 s. During the second and third spin-coatings, a hot air-blowing method was applied [19]. Temperatures of the cells during the air-blowing were set at 90 °C. A polysilane solution was prepared by mixing chlorobenzene (Fujifilm Wako Pure Chemical Corporation, 0.5 mL) with DPPS (Osaka Gas Chemicals, Osaka, Japan, OGSOL SI-30-10, 10 mg). During the last 15 s of the third spin-coating of the perovskite precursor solutions, the DPPS polysilane solution was also spin-coated on the perovskite layer [24]. The prepared cells were then annealed at 180 and 200 °C for 10 min, and at 220 °C for 5 min in ambient air.

Hole transporting layers were spin-coated at 4000 rpm for 30 s. A precursor solution of the hole transporting layer was prepared by mixing chlorobenzene (0.5 mL; Wako Pure Chemical Industries, Osaka, Japan) and spiro-OMeTAD (Sigma Aldrich, St. Louis, MO, USA, 36.1 mg) for 24 h. An acetonitrile (Nacalai Tesque, Kyoto, Japan, 0.5 mL) solution of lithium bis(trifluoromethylsulfonyl)imide (Tokyo Chemical Industry, 260 mg) was similarly prepared by 24 h stirring. This lithium bis(trifluoromethylsulfonyl)imide solution (8.8 μL) was added to the spiro-OMeTAD solution mixed with 4-*tert*-butylpyridine (Sigma Aldrich, 14.4 μL) and stirred at 70 °C for 30 min. Lastly, top-electrodes of gold (Au) were formed by a vacuum evaporating system (Sanyu Electron, Tokyo, Japan, SVC-700TMSG). All the fabricated devices were stored at 22 °C and ~30% humidity in ambient air.

The current density voltage characteristics (Keysight, Santa Rosa, CA, USA, B2901A) of the fabricated devices were measured under a solar simulating light source (San-ei Electric, Osaka, Japan, XES-301S) operated at 100 mW cm^{-2} (air mass 1.5). The exposed area of the photovoltaic devices was 0.080 cm^2 . An X-ray diffractometer (Bruker, Billerica, MA, USA, D2 PHASER) was used for microstructural analysis of the perovskite crystals.

3. Results and Discussion

Figure 1 shows conversion efficiency changes of the the $\text{MA}_{0.64}\text{FA}_{0.31}\text{K}_{0.05}\text{PbI}_3$ devices, prepared at 180~220 °C. For the as-prepared devices, those annealed at 200 °C showed the highest conversion efficiency of ~11% and were almost identical to the conversion efficiency after 163 days. For the device annealed at 220 °C, the conversion efficiencies decreased after 50 days. For the device prepared at 180 °C, the conversion efficiency was observed at 1.67%. After 42 days, the open-circuit voltage and short-circuit current density were improved. Furthermore, the fill factor also improved after 131 days. After 163 days, the photovoltaic properties of the $\text{MA}_{0.64}\text{FA}_{0.31}\text{K}_{0.05}\text{PbI}_3$ device were further enhanced, and the highest conversion efficiency of 13.82% were obtained, as shown in Figure 1.

XRD patterns of the perovskite solar cells showed highly (100)-oriented crystals of the perovskite compounds, which were formed by the hot air-blowing method [19]. All devices presented few peaks corresponding to PbI_2 , which indicated the effectiveness of the DPPS layer against high-temperature annealing at ~200 °C. Almost no PbI_2 formation was observed for the $\text{MA}_{0.48}\text{FA}_{0.47}\text{K}_{0.05}\text{PbI}_3$ devices, even after annealing at 220 °C. The FA-rich composition contributed to the stability of the cubic perovskite and suppressed PbI_2 formation.

A schematic model showing the microstructures, carrier dynamics, and stability of the proposed devices is shown in Figure 3a. Since there was no DPPS layer for the standard device, the perovskite

compound decomposed to PbI_2 after several months by the desorption of CH_3NH_3 and influence of oxygen and H_2O in the air. The number of holes and electrons generated in the perovskite layer was therefore reduced and the photovoltaic properties were degraded. However, the stability of the $\text{MAPbI}_3/(\text{DPPS})$ devices improved because DPPS functioned as a protective layer and suppressed decomposition of the perovskite compound. From the XRD results, the peak intensity of 100 perovskite increased after several months. The number of electrons and holes generated in the perovskite layer therefore increased and the photovoltaic properties were slightly improved after several months.

In the present work, chlorobenzene was used as the solvent for the DPPS solution. The chlorobenzene dripping is often used to improve not only crystallinity of perovskite films but also photovoltaic performance of the perovskite solar cells [44,45]. Although the annealing temperature of $100\text{ }^\circ\text{C}$ is enough for the chlorobenzene-dripped devices, the higher annealing temperature of $\sim 200\text{ }^\circ\text{C}$ is necessary for the present DPPS-dripped device. This indicates that the improvement mechanism of the photovoltaic properties would be different from that of the chlorobenzene dripping. The DPPS layer could work as the effective protective layer improving the stability. In addition, the DPPS with the hole transport property would suppress the charge recombination and improve the photovoltaic properties. To explain the charge transport, an energy level diagram of the $\text{FTO}/\text{TiO}_2/\text{Perovskite}/(\text{DPPS})/\text{Spiro-OMeTAD}/\text{Au}$ photovoltaic devices is shown in Figure 3b. Previously reported values are used as the energy levels [46,47]. By irradiating light from the FTO substrate side, electrons and holes were generated in the perovskite layer. Electrons generated in the photoactive layer were transported through TiO_2 to the FTO, and holes were transported through DPPS and spiro-OMeTAD to the Au. By incorporating DPPS between the perovskite and HTL, effective hole transport from the valence band of the perovskite to the Au electrode was induced. This smooth transport was also due to the molecular structure of DPPS [13,16,38].

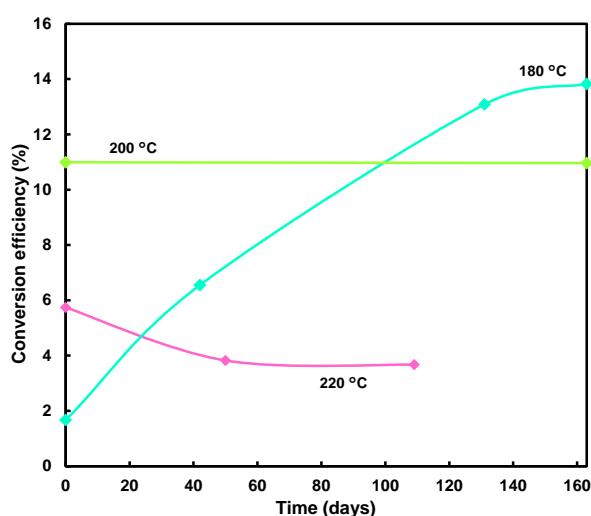


Figure 2. Changes of conversion efficiencies of $\text{MA}_{0.64}\text{FA}_{0.31}\text{K}_{0.05}\text{PbI}_3$ photovoltaic devices prepared at 180, 200, and $220\text{ }^\circ\text{C}$.

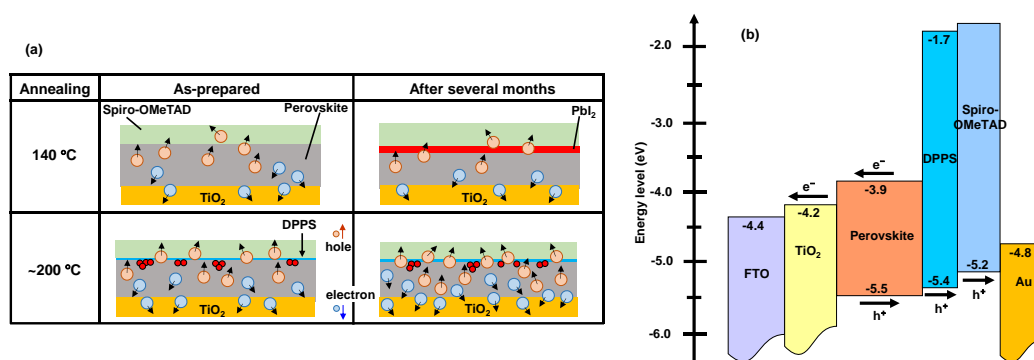


Figure 3. (a) Schematic illustration of microstructures, carrier dynamics and stability for perovskite solar cells under different annealing temperatures. (b) Energy level diagram of the cell.

4. Conclusions

In summary, the effects of inserting a DPPS layer between the perovskite layer and HTL on the photovoltaic properties were investigated. The *J-V* characteristics indicated improvements to the devices upon introducing a DPPS layer on the perovskite layer after annealing at high temperatures. The device annealed at 200–220 °C showed the highest conversion efficiencies among the as-prepared devices. On the other hand, the photovoltaic properties of the device annealed at 180 °C were improved after several months. Microstructures of the perovskite compounds were investigated by XRD, which indicated suppression of PbI₂ formation for the DPPS-added device formed at 180 °C, even after six months. Increased crystallite sizes of the perovskite promoted a decrease of the grain boundary area and point defects, which reduced the current leakage and improved the photovoltaic performance. The present results indicate that polysilane insertion and high-temperature annealing are effective for the improvement of the conversion efficiencies of perovskite photovoltaic devices.

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